

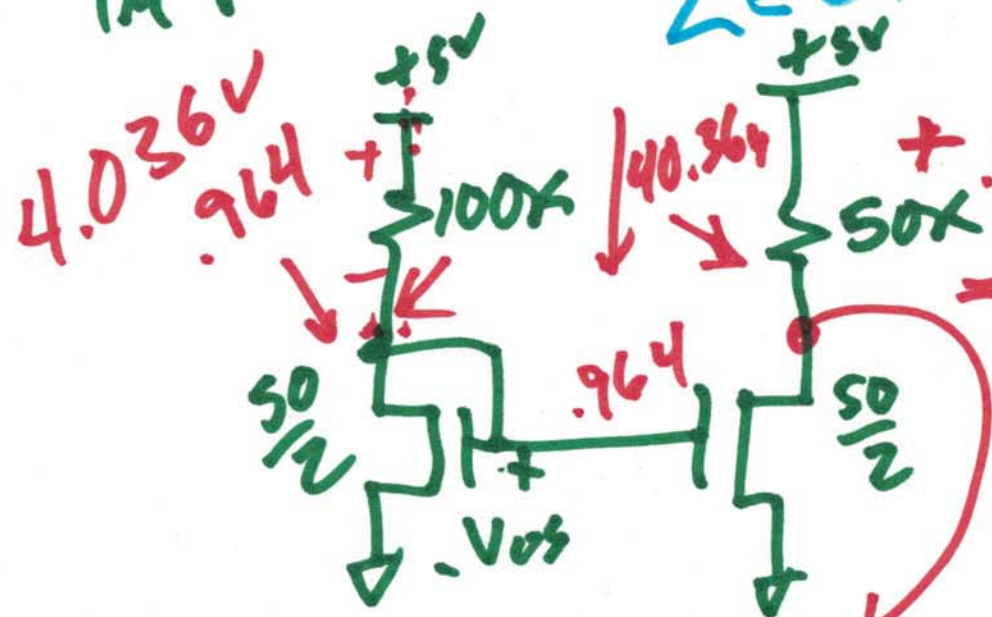
EE 420 / ECG 620

Analog IC Design

2/12/2016

Lecture 9

$K_P = 120 \mu A/V^2$
 $V_{TH} = 0.8$
 1u Process



$$\frac{120 \mu A}{2} \cdot \frac{50}{2} (V_{GS} - 0.8)^2 = \frac{5 - V_{GS}}{100K}$$

$$5 - 40.36 \cdot 50K = 4.518V$$

$$150(V_{GS}^2 - 1.6V_{GS} + 0.64) = 5 - V_{GS}$$

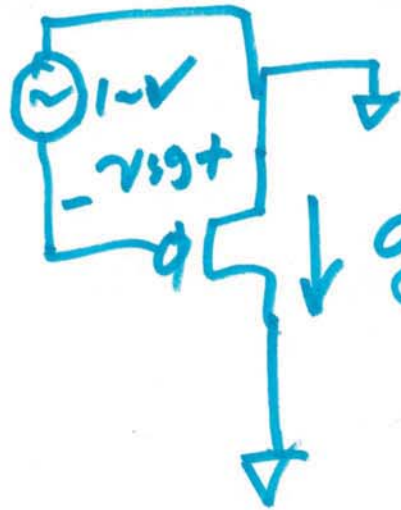
$$150V_{GS}^2 - 240V_{GS} + 96 = 5 - V_{GS}$$

Open book and closed notes.

Show your work for credit.

1. Work problem 9.13 on page 308 if the 1.3 V source is changed to 1.15 and the MOSFET is resized to 30/2. (4 points)

$$k_n = 150 \mu\text{A}/\text{V}^2$$



$$k_n V_{gs} = 150 \mu\text{A} \cdot \frac{1.1\text{V}}{\sqrt{2}}$$

$$i_d = 150 \text{ nA}$$



$$150V_{os}^2 - 239V_{os} + 91 = 0$$

$$V_{os} = \frac{239 \pm \sqrt{239^2 - 4 \cdot 150 \cdot 91}}{300}$$

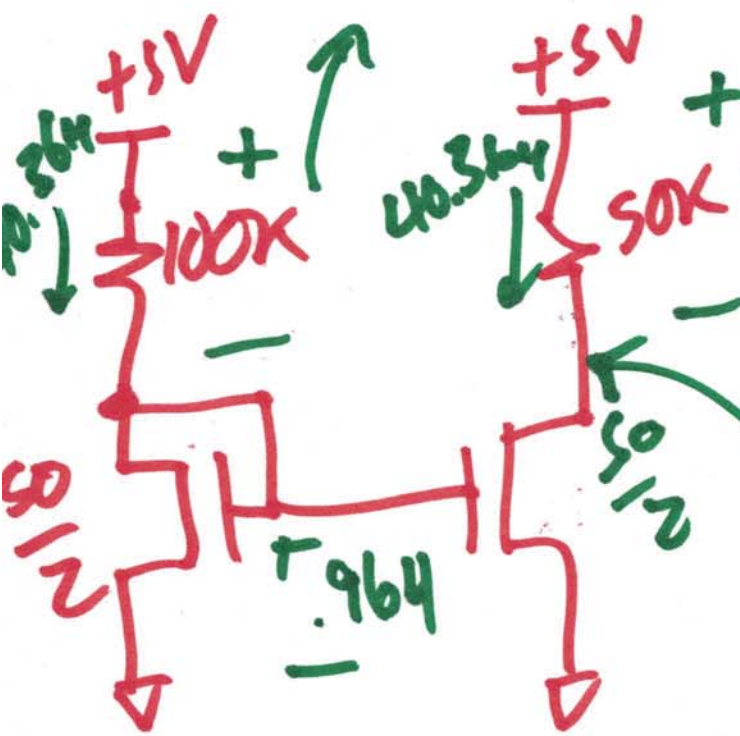
$$2.018V$$

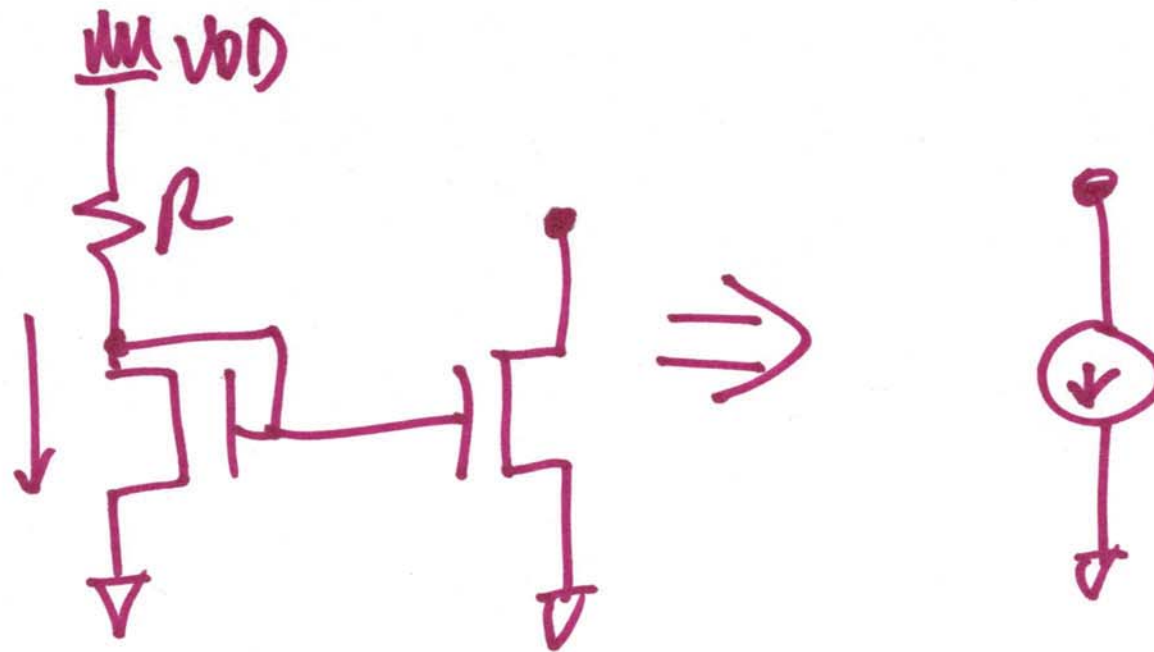
$$V_{os} = 0.964 \text{ or } .0629$$

$$I_D = \frac{5 - .964}{100k} = \frac{4.036}{100k} = \underline{\underline{40.36 \mu A}}$$

$$\underline{\underline{2.982V}}$$

4.036V!





$$\frac{V_{DD} - V_{SG}}{R}$$



$$I_{REF} = \frac{2}{K_P \cdot \frac{W}{L} \cdot R^2} \left(1 - \sqrt{\frac{1}{K}}\right)^2$$

Let's say $K = 4$

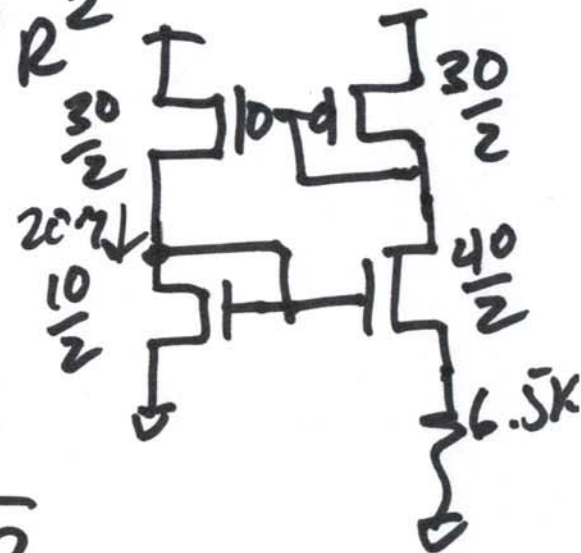
$$I_{REF} = \frac{1}{2 K_P \cdot \frac{W}{L} R^2}$$

$$2 K_P \cdot \frac{W}{L} \cdot I_{REF} = \frac{1}{R^2}$$

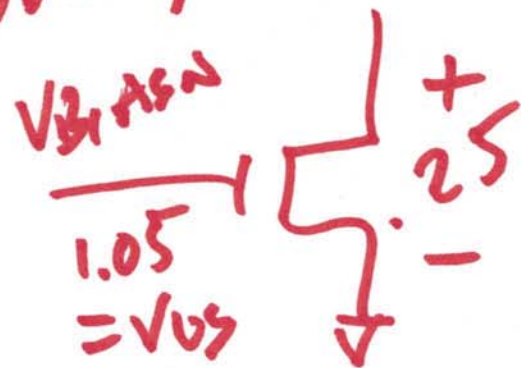
$$g_m = \sqrt{2 K_P \cdot \frac{W}{L} \cdot I_{REF}} = \frac{1}{R}$$

$$= 150 \frac{\mu A}{V}$$

Constant- g_m bias

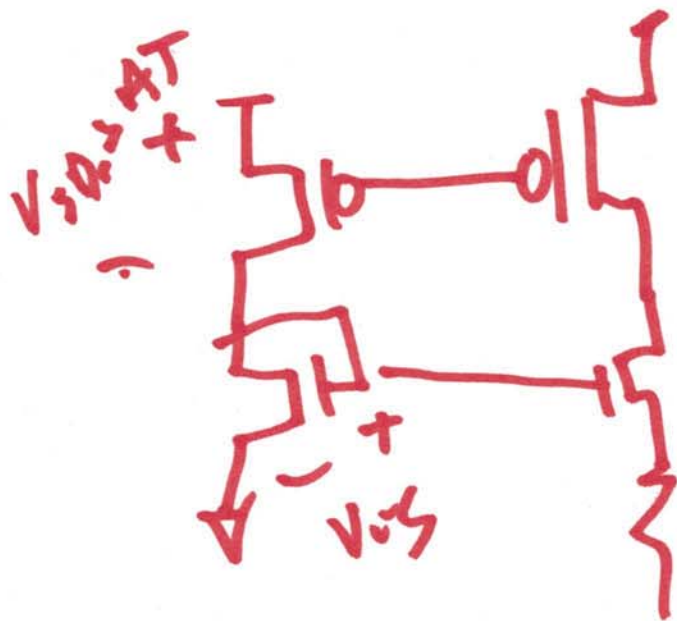


$$-1.15 + 5V - 3.85 = V_{SD} \geq V_{SG} - V_{THP} = 0.25 = V_{SD, SAT}$$



Saturation

$$V_{DS} > \underbrace{V_{GS} - V_{THP}}_{V_{DS, SAT} = V_{OV}}$$



$$V_{DD} > V_{GS} + V_{SD, SAT} = V_{OV} + V_{THP} + V_{SG} - V_{THP}$$